VS-VSKJS440/030

Vishay Semiconductors





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AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS					
I _{F(AV)} 440 A					
V _R	30 V				
Package	AAP Gen 7 (TO-240AA)				
Circuit configuration Two diodes common anode					

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance



- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKJS440/030 Schottky rectifier common anode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS VALUES UN						
I _{F(AV)}	Rectangular waveform	440	A				
V _{RRM}		30	V				
I _{FSM}	t _p = 5 μs sine	27 000	A				
V _F	200 A _{pk} , T _J = 125 °C	0.61	V				
TJ	Range	-55 to +150	°C				

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-VSKJS440/030 UNITS						
Maximum DC reverse voltage	V _R	30	V			
Maximum working peak reverse voltage	V _{RWM}					

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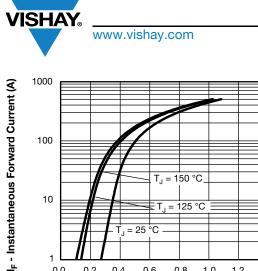
ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDI	VALUES	UNITS		
Maximum average	per module		50 % duty cycle at $T_{\rm C}$ = 97 °C, rectangular waveform		440		
forward current per leg		I _{F(AV)}	50% duly cycle at $T_{\rm C} = 97$ C,	220			
Maximum peak one cycle non-repetitive surge current			5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	27 000	A	
		IFSM	10 ms sine or 6 ms rect. pulse	rated V_{RRM} applied	3000		
Non-repetitive avalanche energ	у	E _{AS}	T _J = 25 °C, I _{AS} = 20 A, L = 1 mH		198	mJ	
Repetitive avalanche current		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		44	А	

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS			
	V _{FM}	220 A	T _{.1} = 25 °C	0.68	V		
Maximum forward voltage drop		440 A	1j=25 0	1.0			
Maximum forward voltage drop		220 A	T 105 %O	0.61			
		440 A	T _J = 125 °C	0.93			
	I _{RM}	T _J = 25 °C	V - Poted V	20	mA		
Maximum reverse leakage current		T _J = 125 °C	V _R = Rated V _R	1120			
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal rang	14 800	pF			
Typical series inductance	L _S	Measured lead to lead 5 m	5.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs			
Maximum RMS insulation voltage	V _{INS}	50 Hz	3000 (1 min) 3600 (1 s)	V			

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C
Maximum thermal resistance, junction to case per leg	junction to case per leg RthJC DC Typical thermal resistance, Bucc		DC operation	0.26	
Typical thermal resistance, case to heatsink per module				0.1	°C/W
				75	g
Approximate weight				2.7	oz.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm
	busbar		spread of the compound.	3	
Case style JEDEC® TO-240A/		TO-240AA co	mpatible		

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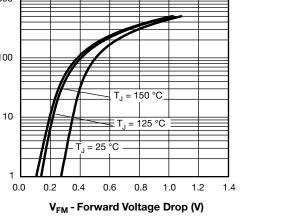
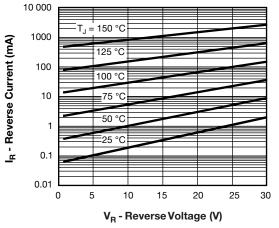
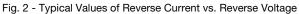


Fig. 1 - Maximum Forward Voltage Drop Characteristics





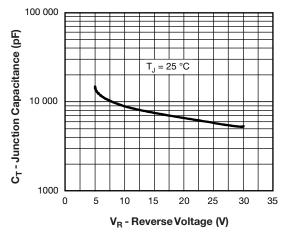


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

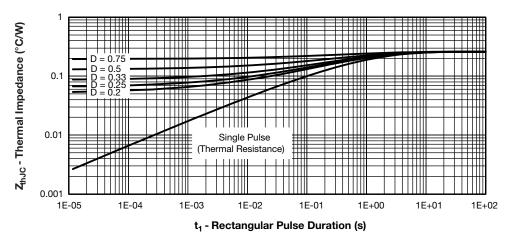


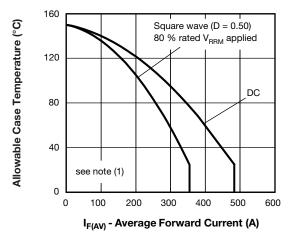
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

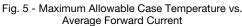
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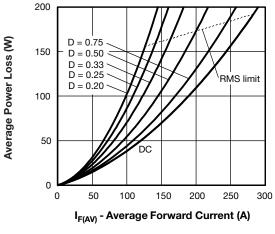


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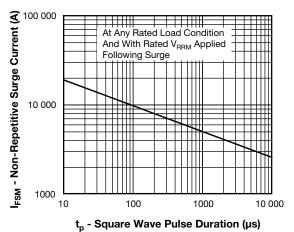


Fig. 7 - Maximum Non-Repetitive Surge Current

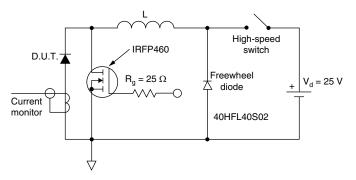


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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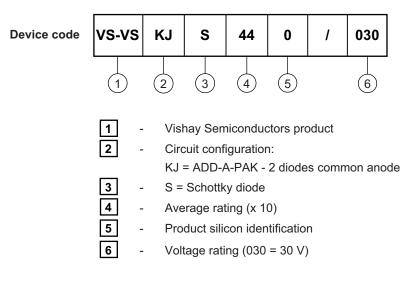
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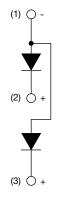
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ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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